



Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
	$2.0\Omega @ V_{GS} = 5.0V$	391mA
60V	2.5Ω @ V _{GS} = 2.5V	368mA
	4.0Ω @ V _{GS} = 1.8V	310mA

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Power-management functions
- Backlighting

60V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN62D2UWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

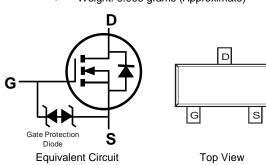
- Package: SOT323
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.006 grams (Approximate)





SOT323

Top View



Ordering Information (Note 4)

Part Number	Paakaga	Packing			
Fait Nulliger	Package	Qty.	Carrier		
DMN62D2UWQ-7	SOT323	3,000	Tape & Reel		
DMN62D2UWQ-13	SOT323	10,000	Tape & Reel		

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Notes:

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

		1		
	2D2	I	Μ	
Τ				_

2D2 = Product Type Marking Code \overline{YM} = Date Code Marking \overline{Y} = Year (ex: K = 2023)

M = Month (ex: 9 = September)

Date	Code	Key
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Date Code Re	, y											
Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	К	L	М	Ν	Р	R	S	Т	U	V	W
	r .			-					-			_
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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^{2.}



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	Vdss	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current (Note 5) $V_{GS} = 5.0V$ State State T _A = +25°C State T _A = +70°C		lo	391 313	mA
Maximum Continuous Body Diode Forward Currer	ls	391	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	Ідм	1.2	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	0.4	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	281	°C/W
Total Power Dissipation (Note 5)		PD	0.6	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	199	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

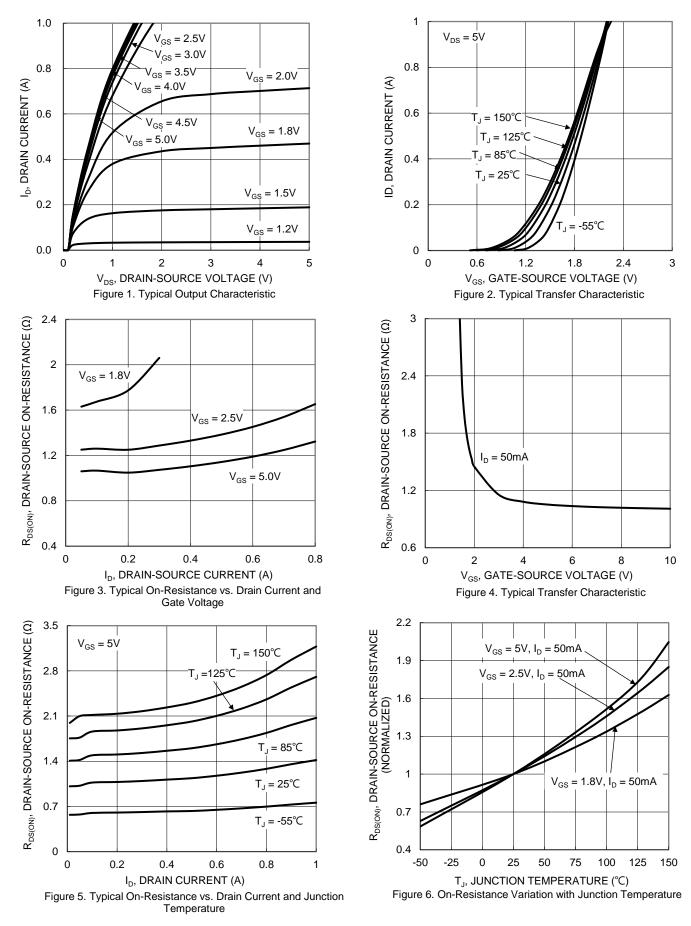
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Cymbol		176	max	Unit	
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	Vgs = 0V, Ip = 250µA
Zero Gate Voltage Drain Current	IDSS	_		1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	0.5		1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
		_	1.1	2.0		V _{GS} = 5.0V, I _D = 0.05A
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.3 2.5	-	-	V _{GS} = 2.5V, I _D = 0.05A
		—	1.7	4.0		V _{GS} = 1.8V, I _D = 0.05A
Diode Forward Voltage	Vsd	_	0.7	1.4	V	V _{GS} = 0V, I _S = 115mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	41	_	pF	
Output Capacitance	Coss		5.4		pF	V _{DS} = 30V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	4.2	_	pF	
Gate Resistance	Rg		52		Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$
Total Gate Charge	Qg		0.8		nC	
Gate-Source Charge	Qgs		0.2		nC	VGS = 4.5V, VDS = 10V ID = 250mA
Gate-Drain Charge	Q _{gd}		0.1		nC	
Turn-On Delay Time	tD(ON)	_	1.5		ns	
Turn-On Rise Time	tR	_	9.7	_	ns	V _{DD} = 30V, V _{GS} = 10V
Turn-Off Delay Time	tD(OFF)	_	22.6	_	ns	$R_g = 25\Omega, I_D = 200 \text{mA}$
Turn-Off Fall Time	tF	_	19.5	_	ns]

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



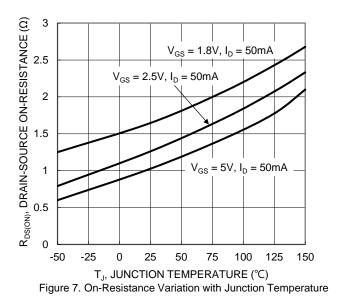
DMN62D2UWQ

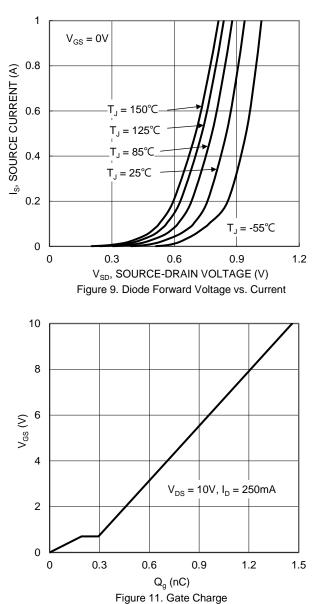


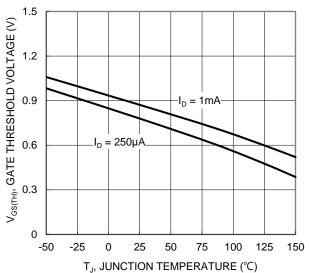
DMN62D2UWQ Document number: DS44899 Rev. 2 - 2

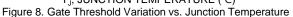


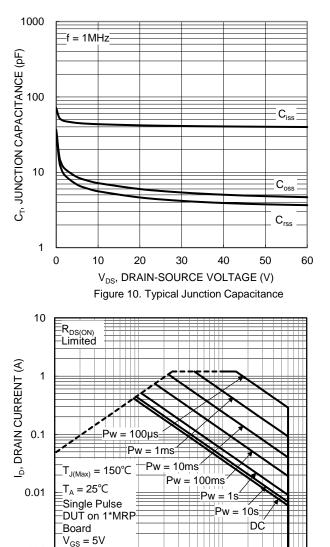








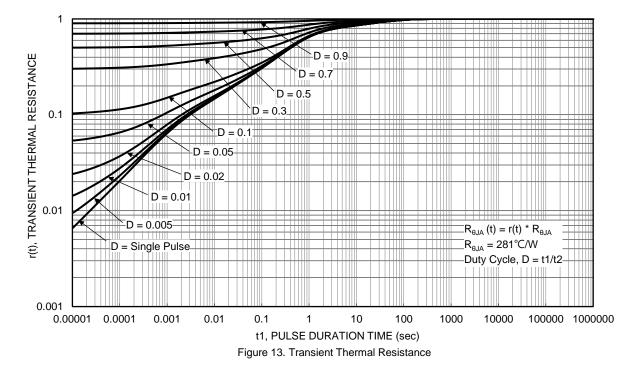




0.001 0.01 1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area

DMN62D2UWQ Document number: DS44899 Rev. 2 - 2

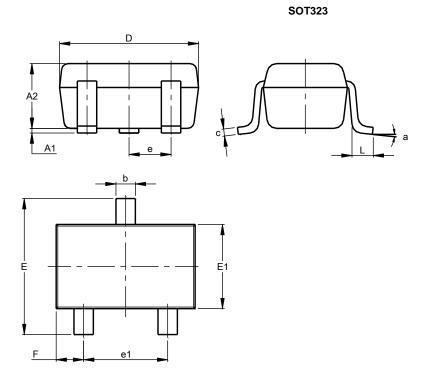






Package Outline Dimensions

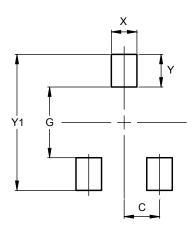
Please see http://www.diodes.com/package-outlines.html for the latest version.



1									
SOT323									
Dim	Min	Max	Тур						
A1	0.00	0.10	0.05						
A2	0.90	1.00	0.95						
b	0.25	0.40	0.30						
c	0.10	0.18	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
e	C).650 B	SC						
e1	1.20	1.40	1.30						
F	0.375	0.475	0.425						
L	0.25	0.40	0.30						
а	0°	8°							
All	Dimen	sions i	in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

SOT323



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